



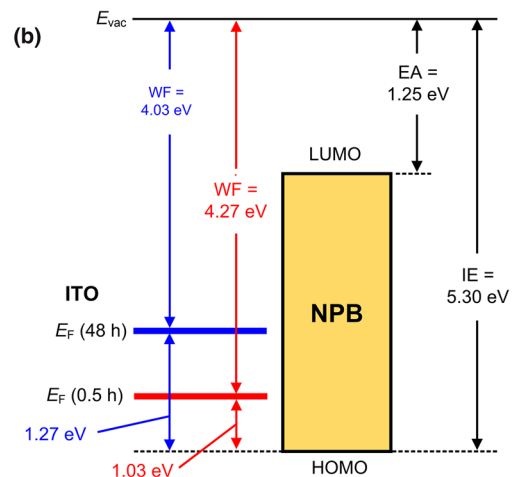
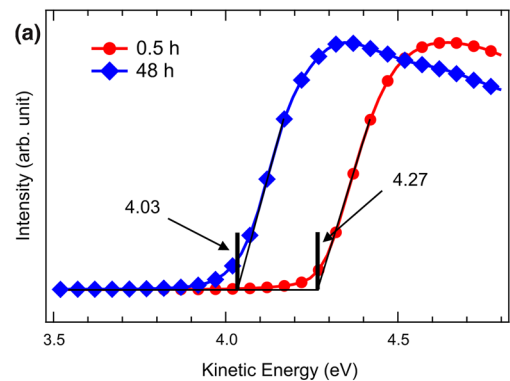
Correction to: Effect of waiting time of indium tin oxide electrode in entry chamber on organic light-emitting diodes

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Due to an unfortunate oversight the position of "EF (0.5 h)" and "EF (48 h)" is given incorrectly. It should read:



The original article can be found online at <https://doi.org/10.1007/s40042-021-00145-8>.

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Fig. 4 **a** UPS spectra of the SEC region of ITO kept for 0.5 and 48 h in the entry chamber. **b** Energy-level diagram of ITO and NPB. E_{vac} , E_F , WF , $LUMO$, $HOMO$, EA , and IE denote the vacuum level, Fermi level, work function, lowest-unoccupied molecular orbital, highest-occupied molecular orbital, electron affinity, and ionization energy, respectively

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